# **MA3J147** (MA147)

## Silicon epitaxial planar type

For high-speed switching circuits

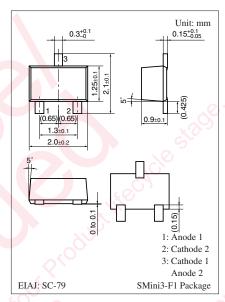
#### ■ Features

- Two isolated elements contained in one package, allowing highdensity mounting
- Two diodes are connected in series in the package

### ■ Absolute Maximum Ratings $T_a = 25$ °C

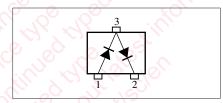
| Parameter                    |        | Symbol          | Rating      | Unit |  |
|------------------------------|--------|-----------------|-------------|------|--|
| Reverse voltage              |        | $V_R$           | 80          | V    |  |
| Maximum peak reverse voltage |        | V <sub>RM</sub> | 80          | V    |  |
| Forward current              | Single | $I_{F}$         | 100         | mA   |  |
|                              | Series |                 | 65          |      |  |
| Peak forward                 | Single | $I_{FM}$        | 225         | mA   |  |
| current                      | Series |                 | 145         |      |  |
| Non-repetitive peak          | Single | $I_{FSM}$       | 500         | mA   |  |
| forward surge current *      | Series |                 | 325         |      |  |
| Junction temperature         |        | T <sub>j</sub>  | 150         | °C   |  |
| Storage temperature          |        | $T_{stg}$       | -55 to +150 | °C   |  |

Note) \*: t = 1 s



Marking Symbol: MS

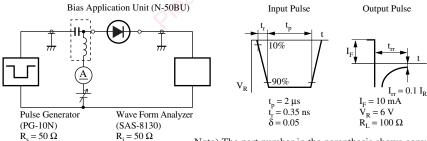
#### Internal Connection



### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

| Parameter               | Symbol          | Conditions                               | Min | Тур | Max | Unit |
|-------------------------|-----------------|--|-----|-----|-----|------|
| Forward voltage         | $V_{\rm F}$     | $I_F = 100 \text{ mA}$                   |     |     | 1.2 | V    |
| Reverse voltage         | $V_R$           | $I_R = 100 \mu A$                        | 80  |     |     | V    |
| Reverse current         | $I_R$           | $V_R = 75 \text{ V}$                     |     |     | 100 | nA   |
| Terminal capacitance    | C <sub>t</sub>  | $V_R = 0 \text{ V, f} = 1 \text{ MHz}$   |     |     | 2   | pF   |
| Reverse recovery time * | t <sub>rr</sub> | $I_F = 10 \text{ mA}, V_R = 6 \text{ V}$ |     |     | 3   | ns   |
|                         |                 | $I_{rr} = 0.1 I_R, R_L = 100 \Omega$     |     |     |     |      |

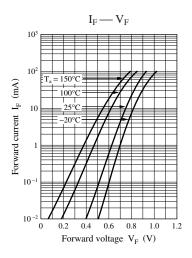
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - 2. Absolute frequency of input and output is 100 MHz.
  - 3. \*: t<sub>rr</sub> measurement circuit

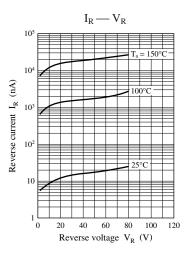


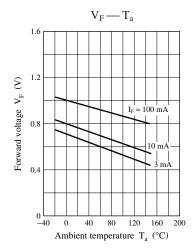
Note) The part number in the parenthesis shows conventional part number.

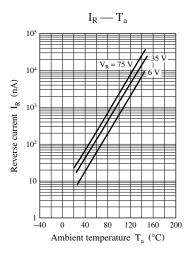
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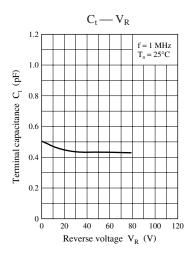
## **Panasonic**

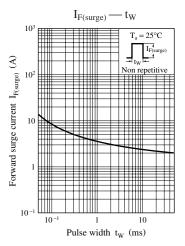












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